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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, I <sup>2</sup> C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, Motor Control PWM, PDR, POR, PVD, PWM, Temp Sensor, WDT
Number of I/O	26
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 10x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	-
Purchase URL	<a href="https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f103c4t6a">https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f103c4t6a</a>

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## 2.1 Device overview

Table 2. STM32F103xx low-density device features and peripheral counts

Peripheral		STM32F103Tx		STM32F103Cx		STM32F103Rx	
Flash - Kbytes		16	32	16	32	16	32
SRAM - Kbytes		6	10	6	10	6	10
Timers	General-purpose	2	2	2	2	2	2
	Advanced-control	1		1		1	
Communication	SPI	1	1	1	1	1	1
	I <sup>2</sup> C	1	1	1	1	1	1
	USART	2	2	2	2	2	2
	USB	1	1	1	1	1	1
	CAN	1	1	1	1	1	1
GPIOs		26		37		51	
12-bit synchronized ADC Number of channels		2 10 channels		2 10 channels		2 16 channels <sup>(1)</sup>	
CPU frequency		72 MHz					
Operating voltage		2.0 to 3.6 V					
Operating temperatures		Ambient temperatures: –40 to +85 °C / –40 to +105 °C (see <a href="#">Table 9</a> ) Junction temperature: –40 to + 125 °C (see <a href="#">Table 9</a> )					
Packages		VFQFPN36		LQFP48, UFQFPN48		LQFP64, TFBGA64	

1. On the TFBGA64 package only 15 channels are available (one analog input pin has been replaced by 'Vref+').

## 2.3 Overview

### 2.3.1 ARM® Cortex™-M3 core with embedded Flash and SRAM

The ARM® Cortex™-M3 processor is the latest generation of ARM® processors for embedded systems. It has been developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced system response to interrupts.

The ARM® Cortex™-M3 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The STM32F103xx performance line family having an embedded ARM core, is therefore compatible with all ARM tools and software.

*Figure 1* shows the general block diagram of the device family.

### 2.3.2 Embedded Flash memory

16 or 32 Kbytes of embedded Flash is available for storing programs and data.

### 2.3.3 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

### 2.3.4 Embedded SRAM

Six or ten Kbytes of embedded SRAM accessed (read/write) at CPU clock speed with 0 wait states.

### 2.3.5 Nested vectored interrupt controller (NVIC)

The STM32F103xx performance line embeds a nested vectored interrupt controller able to handle up to 43 maskable interrupt channels (not including the 16 interrupt lines of Cortex™-M3) and 16 priority levels.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of *late arriving* higher priority interrupts
- Support for tail-chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimal interrupt latency.

### 2.3.6 External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 19 edge detector lines used to generate interrupt/event requests. Each line can be independently configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 51 GPIOs can be connected to the 16 external interrupt lines.

### 2.3.7 Clocks and startup

System clock selection is performed on startup, however the internal RC 8 MHz oscillator is selected as default CPU clock on reset. An external 4-16 MHz clock can be selected, in which case it is monitored for failure. If failure is detected, the system automatically switches back to the internal RC oscillator. A software interrupt is generated if enabled. Similarly, full interrupt management of the PLL clock entry is available when necessary (for example on failure of an indirectly used external crystal, resonator or oscillator).

Several prescalers allow the configuration of the AHB frequency, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the AHB and the high-speed APB domains is 72 MHz. The maximum allowed frequency of the low-speed APB domain is 36 MHz. See [Figure 2](#) for details on the clock tree.

### 2.3.8 Boot modes

At startup, boot pins are used to select one of three boot options:

- Boot from User Flash
- Boot from System Memory
- Boot from embedded SRAM

The boot loader is located in System Memory. It is used to reprogram the Flash memory by using USART1. For further details please refer to AN2606.

### 2.3.9 Power supply schemes

- $V_{DD} = 2.0$  to  $3.6$  V: external power supply for I/Os and the internal regulator. Provided externally through  $V_{DD}$  pins.
- $V_{SSA}$ ,  $V_{DDA} = 2.0$  to  $3.6$  V: external analog power supplies for ADC, reset blocks, RCs and PLL (minimum voltage to be applied to  $V_{DDA}$  is 2.4 V when the ADC is used).  $V_{DDA}$  and  $V_{SSA}$  must be connected to  $V_{DD}$  and  $V_{SS}$ , respectively.
- $V_{BAT} = 1.8$  to  $3.6$  V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when  $V_{DD}$  is not present.

For more details on how to connect power pins, refer to [Figure 11: Power supply scheme](#).

### 2.3.10 Power supply supervisor

The device has an integrated power-on reset (POR)/power-down reset (PDR) circuitry. It is always active, and ensures proper operation starting from/down to 2 V. The device remains

Figure 5. STM32F103xx performance line LQFP48 pinout

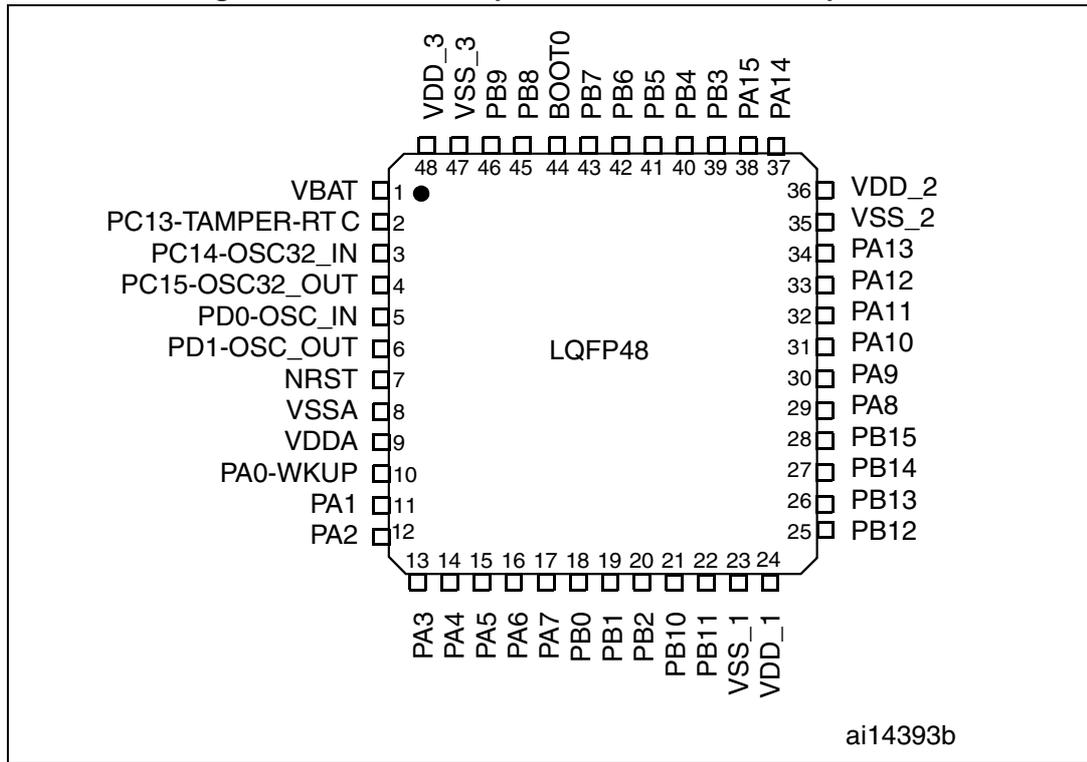


Figure 6. STM32F103xx performance line UFQFP48 pinout

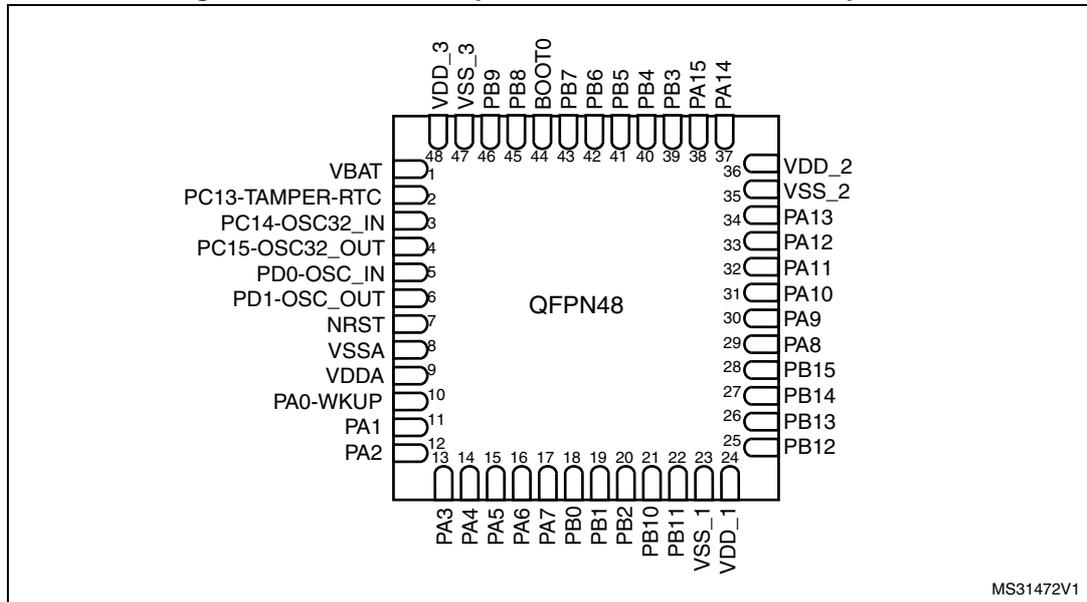


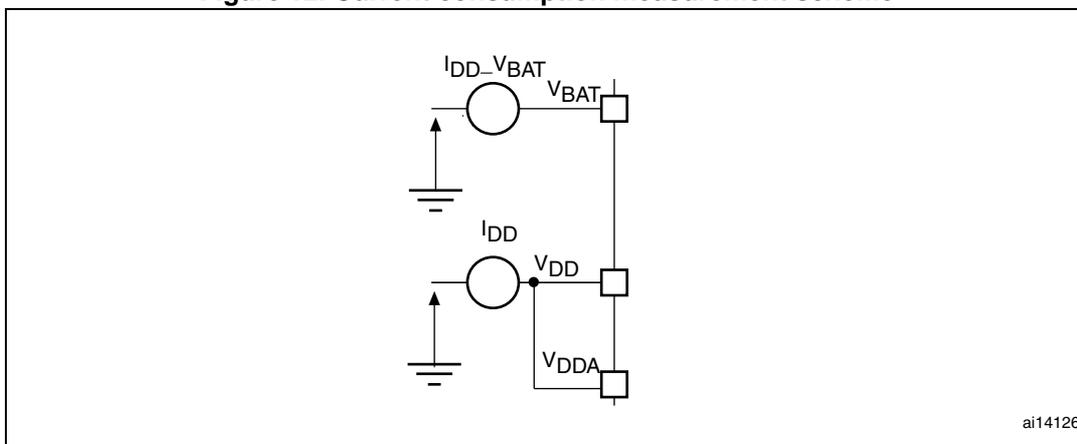
Table 5. Low-density STM32F103xx pin definitions

Pins				Pin name	Type <sup>(1)</sup>	I/O Level <sup>(2)</sup>	Main function <sup>(3)</sup> (after reset)	Alternate functions <sup>(4)</sup>	
LQFP48/ UFQFPN48	LQFP64	TFBGA64	VFQFPN36					Default	Remap
1	1	B2	-	V <sub>BAT</sub>	S	-	V <sub>BAT</sub>	-	-
2	2	A2	-	PC13-TAMPER- RTC <sup>(5)</sup>	I/O	-	PC13 <sup>(6)</sup>	TAMPER-RTC	-
3	3	A1	-	PC14- OSC32_IN <sup>(5)</sup>	I/O	-	PC14 <sup>(6)</sup>	OSC32_IN	-
4	4	B1	-	PC15- OSC32_OUT <sup>(5)</sup>	I/O	-	PC15 <sup>(6)</sup>	OSC32_OUT	-
5	5	C1	2	OSC_IN	I	-	OSC_IN	-	PD0 <sup>(7)</sup>
6	6	D1	3	OSC_OUT	O	-	OSC_OUT	-	PD1 <sup>(7)</sup>
7	7	E1	4	NRST	I/O	-	NRST	-	-
-	8	E3	-	PC0	I/O	-	PC0	ADC12_IN10	-
-	9	E2	-	PC1	I/O	-	PC1	ADC12_IN11	-
-	10	F2	-	PC2	I/O	-	PC2	ADC12_IN12	-
-	11	-	-	PC3	I/O	-	PC3	ADC12_IN13	-
-	-	G1	-	V <sub>REF+</sub> <sup>(8)</sup>	S	-	V <sub>REF+</sub>	-	-
8	12	F1	5	V <sub>SSA</sub>	S	-	V <sub>SSA</sub>	-	-
9	13	H1	6	V <sub>DDA</sub>	S	-	V <sub>DDA</sub>	-	-
10	14	G2	7	PA0-WKUP	I/O	-	PA0	WKUP/USART2_CTS/ ADC12_IN0/ TIM2_CH1_ETR <sup>(9)</sup>	-
11	15	H2	8	PA1	I/O	-	PA1	USART2_RTS/ ADC12_IN1/TIM2_CH2 <sup>(9)</sup>	-
12	16	F3	9	PA2	I/O	-	PA2	USART2_TX/ ADC12_IN2/TIM2_CH3 <sup>(9)</sup>	-
13	17	G3	10	PA3	I/O	-	PA3	USART2_RX/ ADC12_IN3/TIM2_CH4 <sup>(9)</sup>	-
-	18	C2	-	V <sub>SS_4</sub>	S	-	V <sub>SS_4</sub>	-	-
-	19	D2	-	V <sub>DD_4</sub>	S	-	V <sub>DD_4</sub>	-	-
14	20	H3	11	PA4	I/O	-	PA4	SPI1_NSS <sup>(9)</sup> / USART2_CK/ADC12_IN4	-
15	21	F4	12	PA5	I/O	-	PA5	SPI1_SCK <sup>(9)</sup> /ADC12_IN5	-
16	22	G4	13	PA6	I/O	-	PA6	SPI1_MISO <sup>(9)</sup> / ADC12_IN6/TIM3_CH1 <sup>(9)</sup>	TIM1_BKIN
17	23	H4	14	PA7	I/O	-	PA7	SPI1_MOSI <sup>(9)</sup> / ADC12_IN7/TIM3_CH2 <sup>(9)</sup>	TIM1_CH1N
-	24	H5	-	PC4	I/O	-	PC4	ADC12_IN14	-
-	25	H6	-	PC5	I/O	-	PC5	ADC12_IN15	-



### 5.1.7 Current consumption measurement

Figure 12. Current consumption measurement scheme



## 5.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 6: Voltage characteristics](#), [Table 7: Current characteristics](#), and [Table 8: Thermal characteristics](#) may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 6. Voltage characteristics

Symbol	Ratings	Min	Max	Unit
$V_{DD} - V_{SS}$	External main supply voltage (including $V_{DDA}$ and $V_{DD}$ ) <sup>(1)</sup>	-0.3	4.0	V
$V_{IN}^{(2)}$	Input voltage on five volt tolerant pin	$V_{SS} - 0.3$	$V_{DD} + 4.0$	
	Input voltage on any other pin	$V_{SS} - 0.3$	4.0	
$ \Delta V_{DDx} $	Variations between different $V_{DD}$ power pins	-	50	mV
$ V_{SSx} - V_{SS} $	Variations between all the different ground pins	-	50	
$V_{ESD(HBM)}$	Electrostatic discharge voltage (human body model)	see <a href="#">Section 5.3.11: Absolute maximum ratings (electrical sensitivity)</a>		-

1. All main power ( $V_{DD}$ ,  $V_{DDA}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supply, in the permitted range.
2.  $V_{IN}$  maximum must always be respected. Refer to [Table 7: Current characteristics](#) for the maximum allowed injected current values.

Table 11. Embedded reset and power control block characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{PVD}$	Programmable voltage detector level selection	PLS[2:0]=000 (rising edge)	2.1	2.18	2.26	V
		PLS[2:0]=000 (falling edge)	2	2.08	2.16	V
		PLS[2:0]=001 (rising edge)	2.19	2.28	2.37	V
		PLS[2:0]=001 (falling edge)	2.09	2.18	2.27	V
		PLS[2:0]=010 (rising edge)	2.28	2.38	2.48	V
		PLS[2:0]=010 (falling edge)	2.18	2.28	2.38	V
		PLS[2:0]=011 (rising edge)	2.38	2.48	2.58	V
		PLS[2:0]=011 (falling edge)	2.28	2.38	2.48	V
		PLS[2:0]=100 (rising edge)	2.47	2.58	2.69	V
		PLS[2:0]=100 (falling edge)	2.37	2.48	2.59	V
		PLS[2:0]=101 (rising edge)	2.57	2.68	2.79	V
		PLS[2:0]=101 (falling edge)	2.47	2.58	2.69	V
		PLS[2:0]=110 (rising edge)	2.66	2.78	2.9	V
		PLS[2:0]=110 (falling edge)	2.56	2.68	2.8	V
		PLS[2:0]=111 (rising edge)	2.76	2.88	3	V
PLS[2:0]=111 (falling edge)	2.66	2.78	2.9	V		
$V_{PVDhyst}^{(2)}$	PVD hysteresis	-	-	100	-	mV
$V_{POR/PDR}$	Power on/power down reset threshold	Falling edge	1.8 <sup>(1)</sup>	1.88	1.96	V
		Rising edge	1.84	1.92	2.0	V
$V_{PDRhyst}^{(2)}$	PDR hysteresis	-	-	40	-	mV
$T_{RSTTEMPO}^{(2)}$	Reset temporization	-	1	2.5	4.5	ms

1. The product behavior is guaranteed by design down to the minimum  $V_{POR/PDR}$  value.

2. Guaranteed by design, not tested in production.

**Table 18. Typical current consumption in Sleep mode, code running from Flash or RAM**

Symbol	Parameter	Conditions	f <sub>HCLK</sub>	Typ <sup>(1)</sup>		Unit
				All peripherals enabled <sup>(2)</sup>	All peripherals disabled	
I <sub>DD</sub>	Supply current in Sleep mode	External clock <sup>(3)</sup>	72 MHz	12.6	5.3	mA
			48 MHz	8.7	3.8	
			36 MHz	6.7	3.1	
			24 MHz	4.8	2.3	
			16 MHz	3.4	1.8	
			8 MHz	2	1.2	
			4 MHz	1.5	1.1	
			2 MHz	1.25	1	
			1 MHz	1.1	0.98	
			500 kHz	1.05	0.96	
			125 kHz	1	0.95	
		Running on high speed internal RC (HSI), AHB prescaler used to reduce the frequency	64 MHz	10.6	4.2	
			48 MHz	8.1	3.2	
			36 MHz	6.1	2.5	
			24 MHz	4.2	1.7	
			16 MHz	2.8	1.2	
			8 MHz	1.4	0.55	
			4 MHz	0.9	0.5	
			2 MHz	0.7	0.45	
			1 MHz	0.55	0.42	
			500 kHz	0.48	0.4	
			125 kHz	0.4	0.38	

1. Typical values are measures at T<sub>A</sub> = 25 °C, V<sub>DD</sub> = 3.3 V.
2. Add an additional power consumption of 0.8 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is on (ADON bit is set in the ADC\_CR2 register).
3. External clock is 8 MHz and PLL is on when f<sub>HCLK</sub> > 8 MHz.

### 5.3.6 External clock source characteristics

#### High-speed external user clock generated from an external source

The characteristics given in [Table 20](#) result from tests performed using an high-speed external clock source, and under ambient temperature and supply voltage conditions summarized in [Table 9](#).

**Table 20. High-speed external user clock characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{HSE\_ext}$	User external clock source frequency <sup>(1)</sup>	-	1	8	25	MHz
$V_{HSEH}$	OSC_IN input pin high level voltage		$0.7V_{DD}$	-	$V_{DD}$	V
$V_{HSEL}$	OSC_IN input pin low level voltage		$V_{SS}$	-	$0.3V_{DD}$	
$t_{w(HSE)}$ $t_{w(HSE)}$	OSC_IN high or low time <sup>(1)</sup>		5	-	-	ns
$t_{r(HSE)}$ $t_{f(HSE)}$	OSC_IN rise or fall time <sup>(1)</sup>		-	-	20	
$C_{in(HSE)}$	OSC_IN input capacitance <sup>(1)</sup>		-	-	5	-
$DuCy_{(HSE)}$	Duty cycle	-	45	-	55	%
$I_L$	OSC_IN Input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	$\pm 1$	$\mu A$

1. Guaranteed by design, not tested in production.

#### Low-speed external user clock generated from an external source

The characteristics given in [Table 21](#) result from tests performed using an low-speed external clock source, and under ambient temperature and supply voltage conditions summarized in [Table 9](#).

**Table 21. Low-speed external user clock characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{LSE\_ext}$	User External clock source frequency <sup>(1)</sup>	-	-	32.768	1000	kHz
$V_{LSEH}$	OSC32_IN input pin high level voltage		$0.7V_{DD}$	-	$V_{DD}$	V
$V_{LSEL}$	OSC32_IN input pin low level voltage		$V_{SS}$	-	$0.3V_{DD}$	
$t_{w(LSE)}$ $t_{w(LSE)}$	OSC32_IN high or low time <sup>(1)</sup>		450	-	-	ns
$t_{r(LSE)}$ $t_{f(LSE)}$	OSC32_IN rise or fall time <sup>(1)</sup>		-	-	50	
$C_{in(LSE)}$	OSC32_IN input capacitance <sup>(1)</sup>		-	-	5	-
$DuCy_{(LSE)}$	Duty cycle	-	30	-	70	%
$I_L$	OSC32_IN Input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	$\pm 1$	$\mu A$

1. Guaranteed by design, not tested in production.

time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

**Table 23. LSE oscillator characteristics ( $f_{LSE} = 32.768 \text{ kHz}$ )<sup>(1) (2)</sup>**

Symbol	Parameter	Conditions	-	Min	Typ	Max	Unit
$R_F$	Feedback resistor	-	-	-	5	-	MΩ
C	Recommended load capacitance versus equivalent serial resistance of the crystal ( $R_S$ )	$R_S = 30 \text{ K}\Omega$	-	-	-	15	pF
$I_2$	LSE driving current	$V_{DD} = 3.3 \text{ V}$ $V_{IN} = V_{SS}$	-	-	-	1.4	μA
$g_m$	Oscillator transconductance	-	-	5	-	-	μA/V
$t_{SU(LSE)}^{(3)}$	Startup time	$V_{DD}$ is stabilized	$T_A = 50 \text{ }^\circ\text{C}$	-	1.5	-	s
			$T_A = 25 \text{ }^\circ\text{C}$	-	2.5	-	
			$T_A = 10 \text{ }^\circ\text{C}$	-	4	-	
			$T_A = 0 \text{ }^\circ\text{C}$	-	6	-	
			$T_A = -10 \text{ }^\circ\text{C}$	-	10	-	
			$T_A = -20 \text{ }^\circ\text{C}$	-	17	-	
			$T_A = -30 \text{ }^\circ\text{C}$	-	32	-	
			$T_A = -40 \text{ }^\circ\text{C}$	-	60	-	

1. Based on characterization, not tested in production.
2. Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".
3.  $t_{SU(LSE)}$  is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal and it can vary significantly with the crystal manufacturer

**Note:** For  $C_{L1}$  and  $C_{L2}$  it is recommended to use high-quality ceramic capacitors in the 5 pF to 15 pF range selected to match the requirements of the crystal or resonator.  $C_{L1}$  and  $C_{L2}$ , are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of  $C_{L1}$  and  $C_{L2}$ . Load capacitance  $C_L$  has the following formula:  $C_L = C_{L1} \times C_{L2} / (C_{L1} + C_{L2}) + C_{stray}$  where  $C_{stray}$  is the pin capacitance and board or trace PCB-related capacitance. Typically, it is between 2 pF and 7 pF.

**Caution:** To avoid exceeding the maximum value of  $C_{L1}$  and  $C_{L2}$  (15 pF) it is strongly recommended to use a resonator with a load capacitance  $C_L \leq 7 \text{ pF}$ . Never use a resonator with a load capacitance of 12.5 pF.  
**Example:** if you choose a resonator with a load capacitance of  $C_L = 6 \text{ pF}$ , and  $C_{stray} = 2 \text{ pF}$ , then  $C_{L1} = C_{L2} = 8 \text{ pF}$ .

### 5.3.11 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

**Table 32. ESD absolute maximum ratings**

Symbol	Ratings	Conditions	Class	Maximum value <sup>(1)</sup>	Unit
V <sub>ESD(HBM)</sub>	Electrostatic discharge voltage (human body model)	T <sub>A</sub> = +25 °C conforming to JESD22-A114	2	2000	V
V <sub>ESD(CDM)</sub>	Electrostatic discharge voltage (charge device model)	T <sub>A</sub> = +25 °C conforming to JESD22-C101	II	500	

1. Based on characterization results, not tested in production.

#### Static latch-up

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

These tests are compliant with EIA/JESD 78A IC latch-up standard.

**Table 33. Electrical sensitivities**

Symbol	Parameter	Conditions	Class
LU	Static latch-up class	T <sub>A</sub> = +105 °C conforming to JESD78A	II level A

### SPI interface characteristics

Unless otherwise specified, the parameters given in [Table 42](#) are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 9](#).

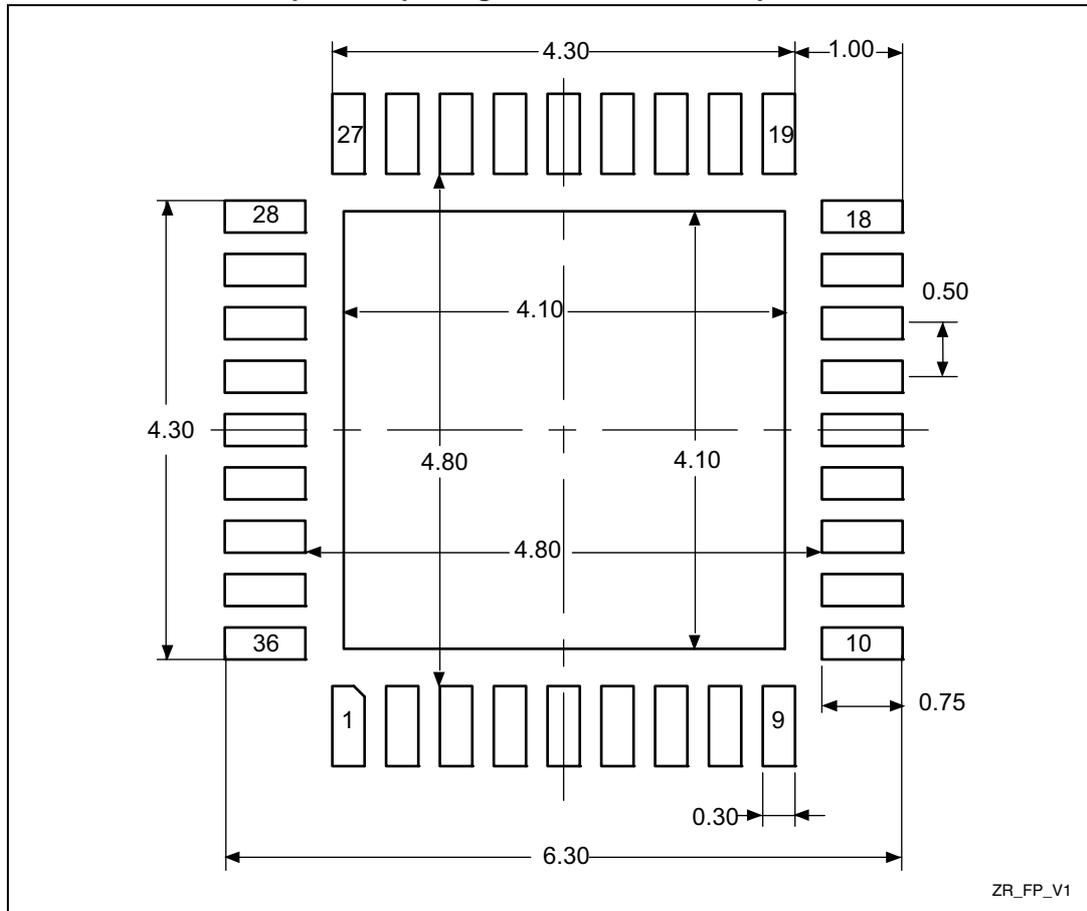
Refer to [Section 5.3.12: I/O current injection characteristics](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO).

**Table 42. SPI characteristics**

Symbol	Parameter	Conditions	Min	Max	Unit
$f_{SCK}$ $1/t_{c(SCK)}$	SPI clock frequency	Master mode	-	18	MHz
		Slave mode	-	18	
$t_{r(SCK)}$ $t_{f(SCK)}$	SPI clock rise and fall time	Capacitive load: C = 30 pF		8	ns
DuCy(SCK)	SPI slave input clock duty cycle	Slave mode	30	70	%
$t_{su(NSS)}^{(1)}$	NSS setup time	Slave mode	$4t_{PCLK}$	-	ns
$t_{h(NSS)}^{(1)}$	NSS hold time	Slave mode	$2t_{PCLK}$	-	
$t_{w(SCKH)}^{(1)}$ $t_{w(SCKL)}^{(1)}$	SCK high and low time	Master mode, $f_{PCLK} = 36$ MHz, presc = 4	50	60	
$t_{su(MI)}^{(1)}$ $t_{su(SI)}^{(1)}$	Data input setup time	Master mode	5	-	
		Slave mode	5	-	
$t_{h(MI)}^{(1)}$ $t_{h(SI)}^{(1)}$	Data input hold time	Master mode	5	-	
		Slave mode	4	-	
$t_{a(SO)}^{(1)(2)}$	Data output access time	Slave mode, $f_{PCLK} = 20$ MHz	0	$3t_{PCLK}$	
$t_{dis(SO)}^{(1)(3)}$	Data output disable time	Slave mode	2	10	
$t_{v(SO)}^{(1)}$	Data output valid time	Slave mode (after enable edge)	-	25	
$t_{v(MO)}^{(1)}$	Data output valid time	Master mode (after enable edge)	-	5	
$t_{h(SO)}^{(1)}$ $t_{h(MO)}^{(1)}$	Data output hold time	Slave mode (after enable edge)	15	-	
		Master mode (after enable edge)	2	-	

1. Based on characterization, not tested in production.
2. Min time is for the minimum time to drive the output and the max time is for the maximum time to validate the data.
3. Min time is for the minimum time to invalidate the output and the max time is for the maximum time to put the data in Hi-Z

Figure 39. VFQFPN36 - 36-pin, 6x6 mm, 0.5 mm pitch very thin profile fine pitch quad flat package recommended footprint



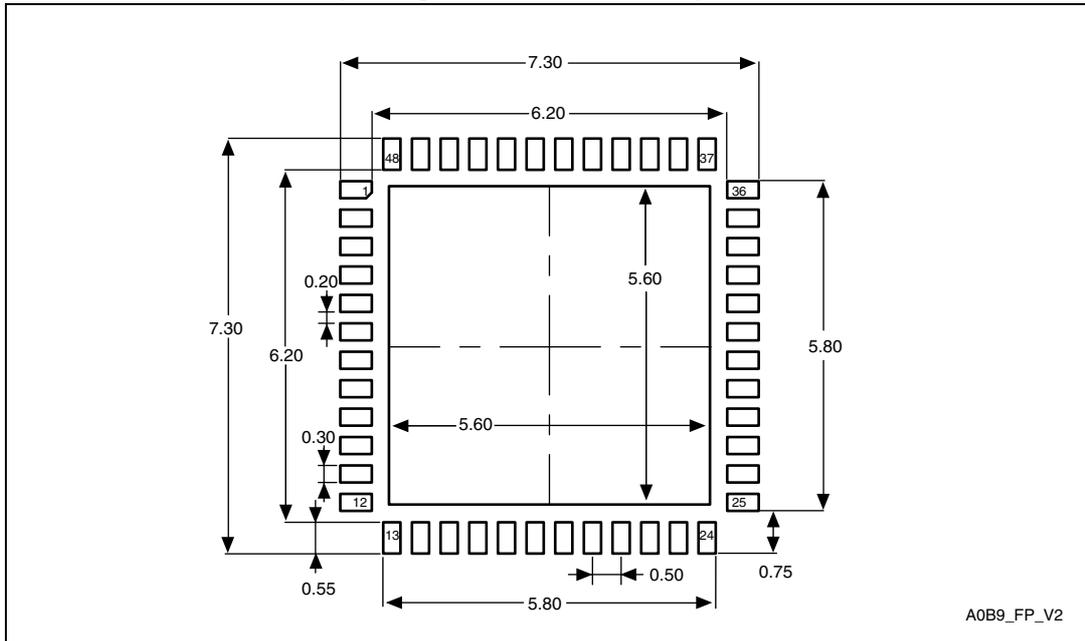
1. Dimensions are expressed in millimeters.

**Table 52. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package mechanical data**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	0.500	0.550	0.600	0.0197	0.0217	0.0236
A1	0.000	0.020	0.050	0.0000	0.0008	0.0020
D	6.900	7.000	7.100	0.2717	0.2756	0.2795
E	6.900	7.000	7.100	0.2717	0.2756	0.2795
D2	5.500	5.600	5.700	0.2165	0.2205	0.2244
E2	5.500	5.600	5.700	0.2165	0.2205	0.2244
L	0.300	0.400	0.500	0.0118	0.0157	0.0197
T	-	0.152	-	-	0.0060	-
b	0.200	0.250	0.300	0.0079	0.0098	0.0118
e	-	0.500	-	-	0.0197	-
ddd	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 42. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package recommended footprint**



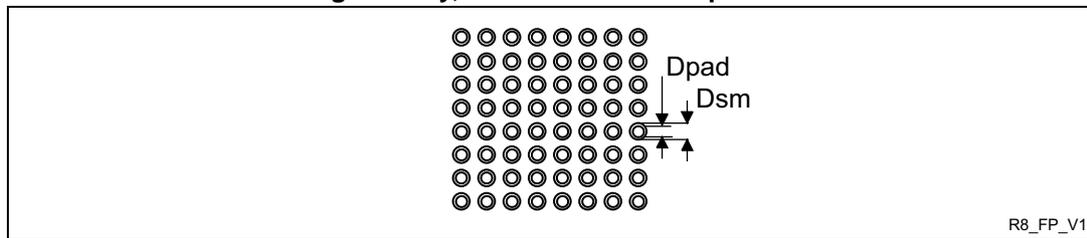
1. Dimensions are expressed in millimeters.

**Table 54. TFBGA64 – 64-ball, 5 x 5 mm, 0.5 mm pitch, thin profile fine pitch ball grid array package mechanical data (continued)**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
e	-	0.500	-	-	0.0197	-
F	-	0.750	-	-	0.0295	-
ddd	-	-	0.080	-	-	0.0031
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.050	-	-	0.0020

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 48. TFBGA64 – 64-ball, 5 x 5 mm, 0.5 mm pitch, thin profile fine pitch ball grid array, recommended footprint**



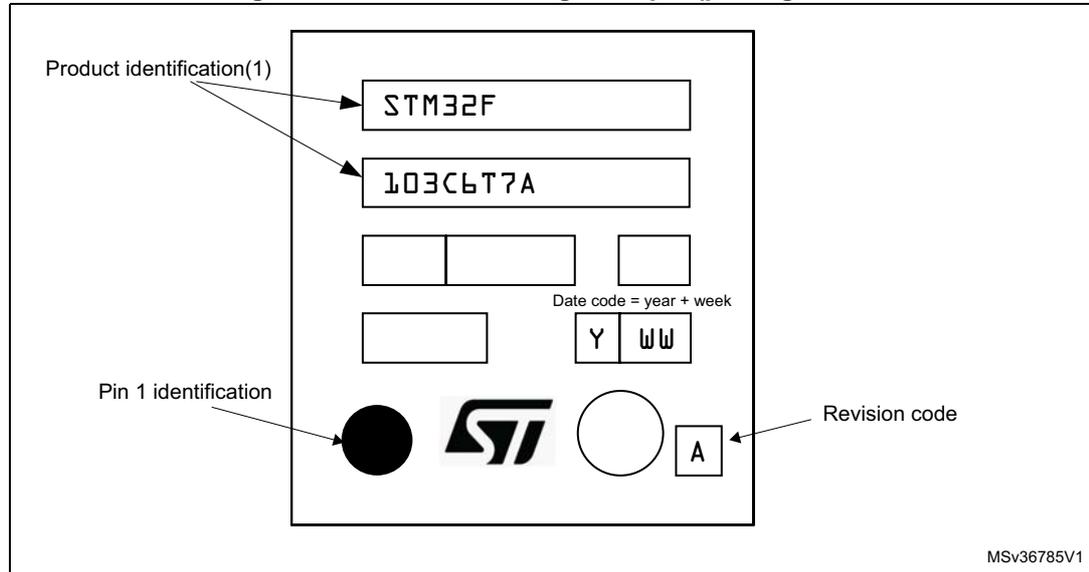
**Table 55. TFBGA64 recommended PCB design rules (0.5 mm pitch BGA)**

Dimension	Recommended values
Pitch	0.5
Dpad	0.280 mm
Dsm	0.370 mm typ. (depends on the soldermask registration tolerance)
Stencil opening	0.280 mm
Stencil thickness	Between 0.100 mm and 1.125 mm
Pad trace width	0.100 mm

**Device Marking for LQFP48**

The following figure gives an example of topside marking orientation versus ball 1 identifier location.

**Figure 52. LQFP48 marking example (package view)**



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.